

1110-97825 PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Appl. No.	: 10/586,445)	Confirmation No.: 4877
Applicant	: NAKAMURA et al.)	
Filed	: 17 July 2006)	
Art Unit	: 1792)	
Examiner	: KUNEMUND)	
Docket No.	: 1110-97825)	
Customer No.:	24628)	
Title:	METHOD FOR PREDICTING PRECIPITATION BEHAVIOR OF OXYGEN IN SILICON SINGLE CRYSTAL, METHOD FOR DETERMINING PRODUCTION PARAMETER OF SILICON SINGLE CRYSTAL, AND STORAGE MEDIUM FOR STORING PROGRAM FOR PREDICTING PRECIPITATION BEHAVIOR OF OXYGEN IN SILICON SINGLE CRYSTAL)	

AMENDMENT

Commissioner for Patents
P.O. Box 1450
Alexandria, Virginia 22313-1450

Dear Sir:

The Office Action of 10 March 2010 has been carefully reviewed and the following amendments and remarks are made in response thereto:

Amendments to the Claims begin on page 2 of this paper.

Remarks/Arguments begin on page 6 of this paper.